# **Preliminary**

TOSHIBA Photocoupler GaAlAs IRED + Photo IC

# **TLP705**

Plasma Display Panel.
Industrial Inverter
IGBT/Power MOS FET Gate Drive

The TOSHIBA TLP705 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 6-lead SDIP package. TLP705 is 50% smaller than 8PIN DIP and has suited the safety standard reinforced insulation class.

So mounting area in safety standard required equipment can be reduced. TLP705 is suitable for gate driving circuit of IGBT or power MOS FET. Especially TLP705 is capable of "direct" gate drive of lowr Power IGBTs.

Peak output current : ±0.45 A (max)
 Operating frequency : 250kHz (max)
 Guaranteed performance over temperature : -40 to 100°C
 Supply current : 3mA (max)
 Power supply voltage : 10 to 20 V
 Threshold input current : I<sub>FLH</sub> = 8 mA (max)

Switching time (t<sub>pLH</sub> / t<sub>pHL</sub>) : 200 ns (max)
 Common mode transient immunity : 10 kV/µs
 Isolation voltage : 5000 Vrms

UL Recognized :UL1577, File No.E67349

Construction Mechanical Rating

	7.62 mm pich standard type	10.16 mm pich TLPXXXF type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.4 mm (Min)	0.4 mm (Min)

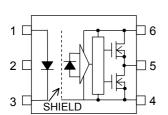
# Unit in mm 4.58±0.25 6 5 4 1 2 3 9 9 9 7.62±0.25 1.27±0.2 1.25±0.25 10.0max 11-5J1 TOSHIBA 11-5J1

Weight: 0.26 g (typ.)

### **Truth Table**

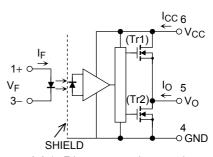
Input	LED	Tr1	Tr2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	L

### Pin Configuration (top view)



- 1: Anode
- 2: NC
- 3: Cathode
- 4: GND
- 5: V<sub>O</sub> (output)
- 6: V<sub>CC</sub>

### **Schematic**



A 0.1  $\mu\text{F}$  bypass capacitor must be connected between pin 6 and 4. (See Note 6)

# Maximum Ratings (Ta = 25°C)

	Characteristics		Symbol	Rating	Unit
	Forward current		lF	20	mA
	Forward current derating (Ta ≥ 85°C)			-0.54	mA/°C
LED	Peak transient forward current	(Note 1)	I <sub>FP</sub>	1	Α
	Reverse voltage		V <sub>R</sub>	5	V
	Junction temperature		Tj	125	°C
	"H" peak output current	(Note 2)	I <sub>OPH</sub>	-0.45	Α
or	"L" peak output current	(Note 2)	I <sub>OPL</sub>	0.45	Α
Detector	Output voltage		Vo	25	V
۵	Supply voltage		V <sub>CC</sub>	25	V
	Junction temperature		Tj	125	°C
Ope	rating frequency	(Note 3)	f	250	kHz
Stora	age temperature range		T <sub>stg</sub>	-55 to 125	°C
Operating temperature range			T <sub>opr</sub>	-40 to 100	°C
Lead	soldering temperature (10 s)	(Note 4)	T <sub>sol</sub>	260	°C
Isola	tion voltage (AC, 1 minute, R.H. ≤ 60%)	(Note 5)	BVS	5000	Vrms

- Note 1: Pulse width  $P_W \le 1\mu s$ , 300 pps
- Note 2: Exponential waveform pulse width  $P_W \le 10 \ \mu s$  ,  $f \le 15 \ kHz$
- Note 3: Exponential waveform loph ≤-0.25 A (≤80 ns) , lopL ≤+0.25 A (≤80 ns) ,Ta =100 °C
- Note 4: It is effective soldering area of Lead .
- Note 5: Device considerd a two terminal device: pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.
- Note 6: A ceramic capacitor(0.1 µF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property.

  The total lead length between capacitor and coupler should not exceed 1 cm.

## **Recommended Operating Conditions**

Characteristics		Symbol	Min	Тур.	Max	Unit
Input current, ON	(Note 7)	I <sub>F (ON)</sub>	10	_	15	mA
Input voltage, OFF		V <sub>F (OFF)</sub>	0	_	0.8	V
Supply voltage		V <sub>CC</sub>	10	_	20	V
Peak output current		I <sub>OPH</sub> / I <sub>OPL</sub>	_	_	± 0.15	Α
Operating temperature		T <sub>opr</sub>	- 40	_	100	°C

Note 7: Input signal rise time (fall time)  $< 0.5 \mu s$ .

# Electrical Characteristics (Ta = -40 to 100°C, unless otherwise specified)

Characteristics	Characteristics Symbol Test Circu Test Condition it		Min	Тур.*	Max	Unit			
Forward voltage		V <sub>F</sub>	_	$I_F = 10 \text{ mA}, Ta = 2$	25°C	_	1.6	1.8	V
Temperature coefficient of forward voltage		ΔV <sub>F</sub> /ΔTa	_	I <sub>F</sub> = 10 mA		_	-2.0	_	mV/°C
Input reverse current		I <sub>R</sub>	_	V <sub>R</sub> = 5 V, Ta = 25	°C	_	_	10	μА
Input capacitance		C <sub>T</sub>	_	V = 0 V , f = 1 MH	z,Ta = 25°C	_	45	_	pF
(4.17)	"H" Level	I <sub>OPH1</sub>	1	V <sub>CC</sub> = 15 V	V <sub>6-5</sub> = 4 V	-0.15	-0.35	_	- A
Output current	H Level	I <sub>OPH2</sub>	'	$V_{CC} = 15 \text{ V}$ $I_F = 10 \text{ mA}$	V <sub>6-5</sub> = 10 V	-0.3	-0.6	_	
(Note 8)	"L" Level	I <sub>OPL1</sub>	2	V <sub>CC</sub> = 15 V I <sub>F</sub> = 0 mA	V <sub>5-4</sub> = 2 V	0.15	0.36	_	
		I <sub>OPL2</sub>			V <sub>5-4</sub> = 10 V	0.3	0.62	_	
Output voltage	"H" Level	V <sub>OH</sub>	3		$I_O = -100 \text{ mA},$ $I_F = 10 \text{ mA}$	6.0	8.5		- V
Output voltage	"L" Level	V <sub>OL</sub>	4	V <sub>CC</sub> = 10 V	I <sub>O</sub> = 100 mA, V <sub>F</sub> = 0.8 V	_	0.4	1.0	
O	"H" Level	Іссн	5	V <sub>CC</sub> = 10 to 20 V	I <sub>F</sub> = 10 mA	_	2.0	3.0	mA
Supply current	"L" Level	ICCL	6	V <sub>O</sub> open	I <sub>F</sub> = 0 mA	_	2.0	3.0	
Threshold input current	$L\toH$	I <sub>FLH</sub>	_	V <sub>CC</sub> = 15 V, V <sub>O</sub> > 1 V		_	2.5	8	mA
Threshold input voltage	$H\toL$	V <sub>FHL</sub>	_	V <sub>CC</sub> = 15 V, V <sub>O</sub> < 1 V		0.8	_	_	V
Supply voltage		V <sub>CC</sub>	_		A 30	10	_	20	V

<sup>\*:</sup> All typical values are at Ta = 25°C

Note 8: Duration of I<sub>O</sub> time  $\leq$  50  $\mu$ s

Note 9: This product is more sensitive than the conventional product to static electricity (ESD) because of a lowest power consumption design.

General precaution to static electricity (ESD) is necessary for handling this component.

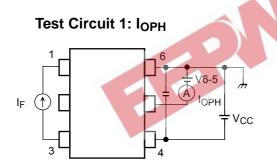
# Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	C <sub>S</sub>	V = 0 V, f = 1MHz (Note 5)	_	1.0	_	pF
Isolation resistance	R <sub>S</sub>	R.H. ≤ 60%,V <sub>S</sub> = 500V (Note 5)	1×10 <sup>12</sup>	10 <sup>14</sup>	-	Ω
	BVS	AC, 1 minute	5000	_	-	Vrms
Isolation voltage		AC, 1 second, in oil	_	10000	_	VIIIIS
		DC,1 minute,in oil	_	10000	-	Vdc

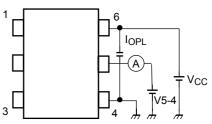
# Switching Characteristics (Ta = -40 to 100°C, unless otherwise specified)

Characteristics		Symbol	Test Circuit	Test C	Condition	Min	Typ.*	Max	Unit
Propagation delay time	$L\toH$	t <sub>pLH</sub>	-		Ta= 25 I <sub>F</sub> = 0 10 mA	70	95	170	
Tropagation delay time	$H \rightarrow L$	t <sub>pHL</sub>			Ta= 25 $I_F = 10 \rightarrow 0 \text{ mA}$	70	105	170	
	$L \to H \qquad t_{pLH}$	Ta= -40 to100 I <sub>F</sub> = 0 10 mA	50	_	200				
Propagation delay time	$H \rightarrow L$	t <sub>pHL</sub>	7	$V_{CC} = 20 \text{ V}$ $R_g = 30 \Omega$ $C_g = 1 \text{ nF}$	Ta= -40 to100 I <sub>F</sub> = 10 0 mA	50	_	200	no
Propagation delay difference between any two parts or channels		tpsk		f=250kHz Duty Cycle =50%	Ta= -40 to100 I <sub>F</sub> = 10 mA	-90	_	90	ns
Pulse Width Distortion		PWD (t <sub>pHL</sub> -t <sub>pLH)</sub>			Ta= -40 to100 I <sub>F</sub> = 10 mA	-65	_	65	
Output rise time (10-90%)		t <sub>r</sub>			$I_F = 0 \rightarrow 10 \text{ mA}$	_	_	_	
Output fall time (90-10%)		t <sub>f</sub>			$I_F = 10 \rightarrow 0 \text{ mA}$	_	_	_	
Common mode transient immunity at hight level output  Common mode transient immunity at low level output  CMH  8		V <sub>CM</sub> = 1000Vp-p	I <sub>F</sub> = 10 mA V <sub>O (min)</sub> = 16 V	-10000	_	_	\//u0		
		CML	8	$V_{CC} = 20 \text{ V}$ $Ta = 25^{\circ}C$	I <sub>F</sub> = 0 mA V <sub>O (max)</sub> = 1 V	10000	_	_	V/μs

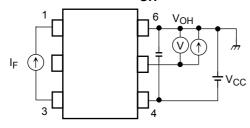
<sup>\*:</sup> All typical values are at Ta = 25°C



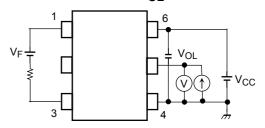




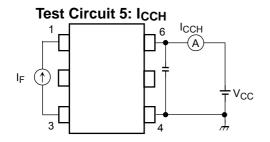
Test Circuit 3: V<sub>OH</sub>

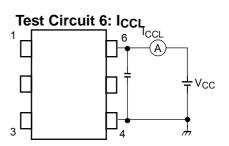


Test Circuit 4: VoL

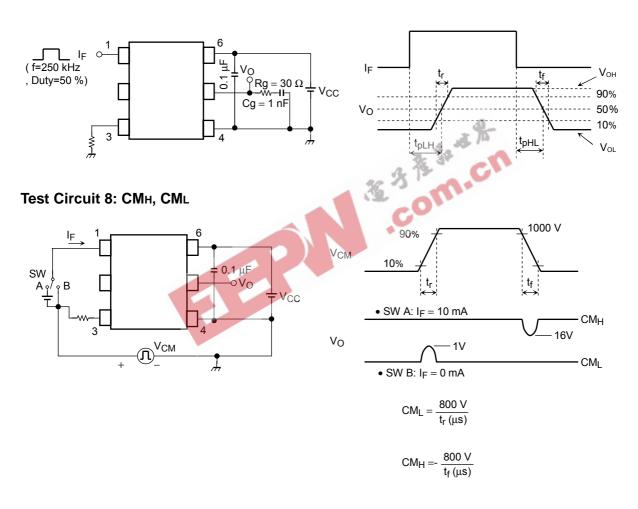


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### Test Circuit 7: tplh, tphl, tr, tf, PWD



 $\text{CM}_{\text{L}}$  (CM<sub>H</sub>) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

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